

2SJ620

Switching Regulator and DC-DC Converter Applications
Motor Drive Applications

- 4-V gate drive
- Low drain-source ON resistance: $R_{DS(ON)} = 63 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 15 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = -100 \text{ }\mu\text{A}$ (max) ($V_{DS} = -100 \text{ V}$)
- Enhancement-model: $V_{th} = -0.8 \text{ to } -2.0 \text{ V}$ ($V_{DS} = -10 \text{ V}$, $I_D = -1 \text{ mA}$)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-100	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	-100	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	-18	A
	Pulse (Note 1)	I_{DP}	-72	
Drain power dissipation ($T_c = 25^\circ\text{C}$)		P_D	125	W
Single pulse avalanche energy (Note 2)		E_{AS}	937	mJ
Avalanche current		I_{AR}	-18	A
Repetitive avalanche energy (Note 3)		E_{AR}	12.5	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	1.0	°C/W

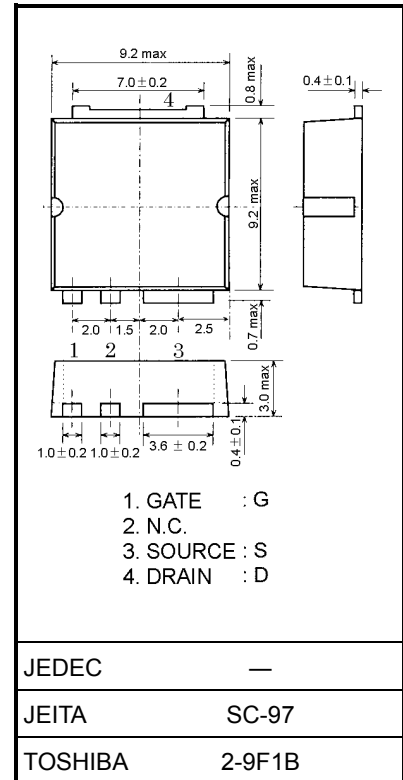
Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: $V_{DD} = -50 \text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 3.56 \text{ mH}$, $R_G = 25 \text{ }\Omega$, $I_{AR} = -18 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

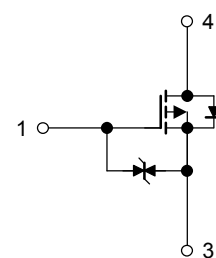
This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm



Weight: 0.74 g (typ.)

Circuit Configuration



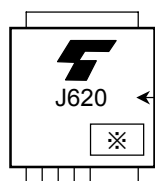
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain cut-OFF current		I_{DSS}	$V_{DS} = -100\text{ V}, V_{GS} = 0\text{ V}$	—	—	-100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-100	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-0.8	—	-2.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = -4\text{ V}, I_D = -9\text{ A}$	—	85	120	m Ω
			$V_{GS} = -10\text{ V}, I_D = -9\text{ A}$	—	63	90	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -6\text{ A}$	7	15	—	S
Input capacitance		C_{iss}	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	2900	—	pF
Reverse transfer capacitance		C_{rss}		—	480	—	
Output capacitance		C_{oss}		—	1000	—	
Switching time	Rise time	t_r	<p>$I_D = -9\text{ A}$ $V_{GS} = 0\text{ V}, -10\text{ V}$ $4.7\ \Omega$ $R_L = 5.55\ \Omega$ $V_{DD} \approx -50\text{ V}$ V_{OUT} $Duty \leq 1\%, t_w = 10\ \mu\text{s}$</p>	—	25	—	ns
	Turn-ON time	t_{on}		—	45	—	
	Fall time	t_f		—	25	—	
	Turn-OFF time	t_{off}		—	170	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx -80\text{ V}, V_{GS} = -10\text{ V}, I_D = -18\text{ A}$	—	140	—	nC
Gate-source charge		Q_{gs}		—	90	—	
Gate-drain ("miller") charge		Q_{gd}		—	50	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	-18	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	-72	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = -18\text{ A}, V_{GS} = 0\text{ V}$	—	—	1.7	V
Reverse recovery time	t_{rr}	$I_{DR} = -18\text{ A}, V_{GS} = 0\text{ V},$	—	220	—	μs
Reverse recovery charge	Q_{rr}	$dI_{DR}/dt = 50\text{ A}/\mu\text{s}$	—	0.97	—	μC

Marking

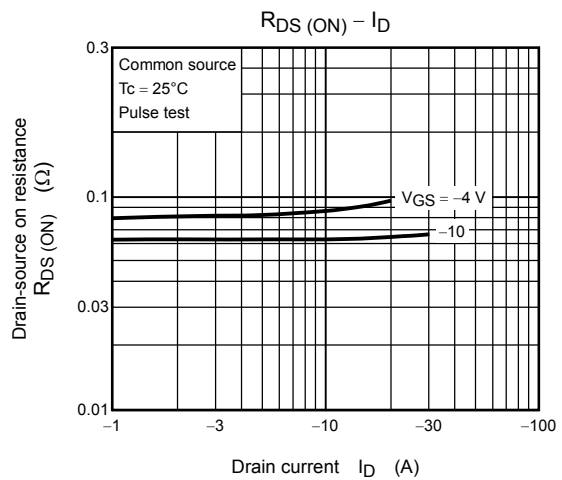
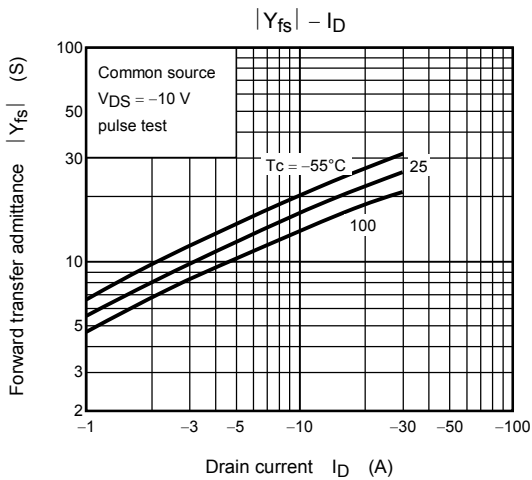
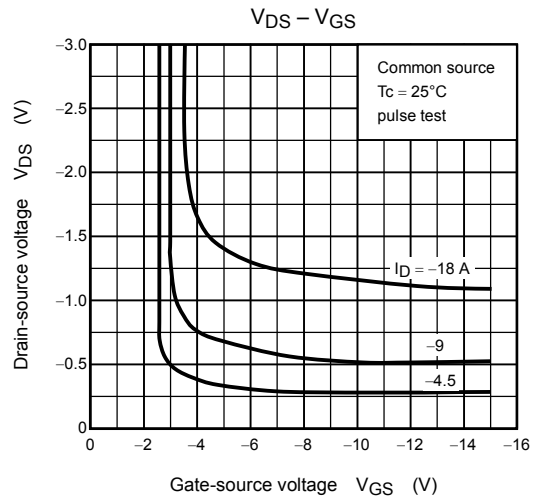
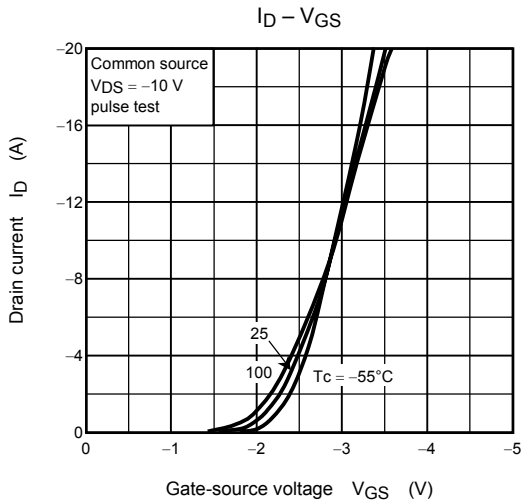
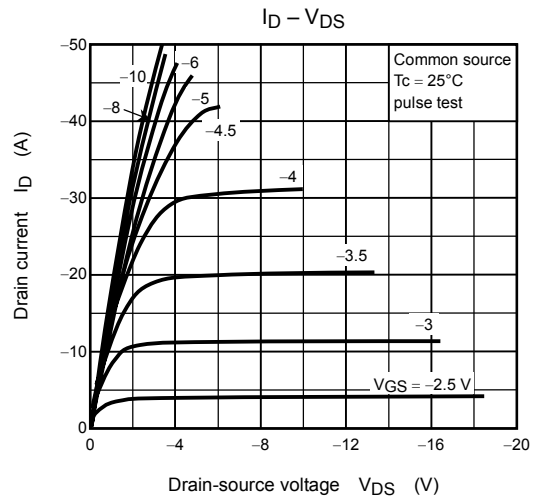
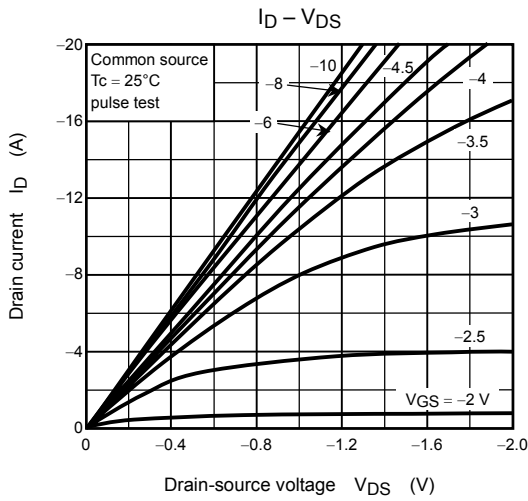


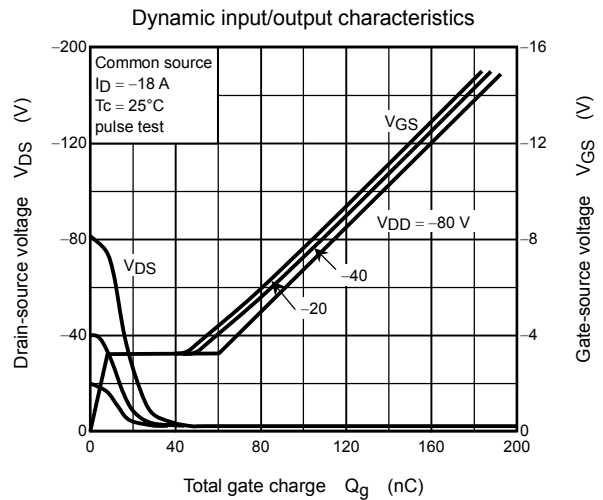
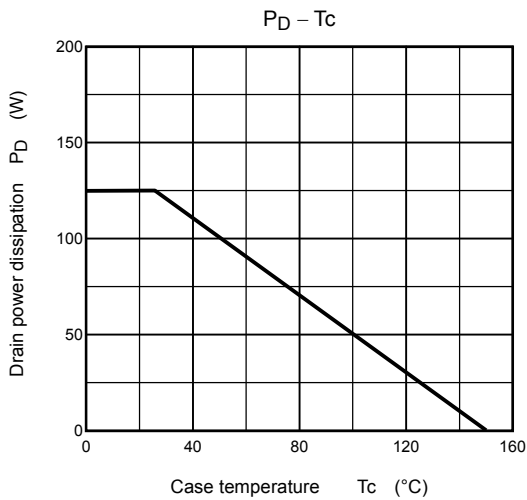
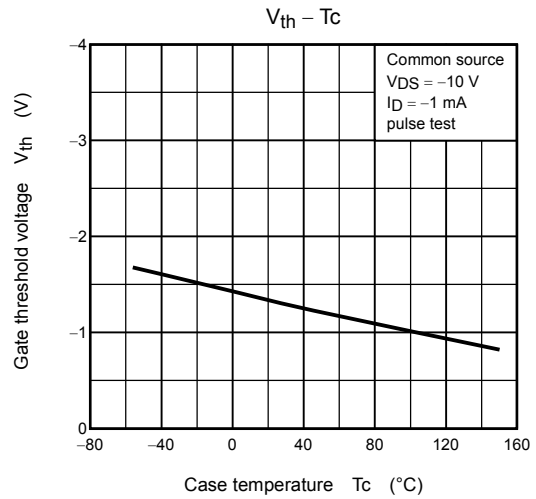
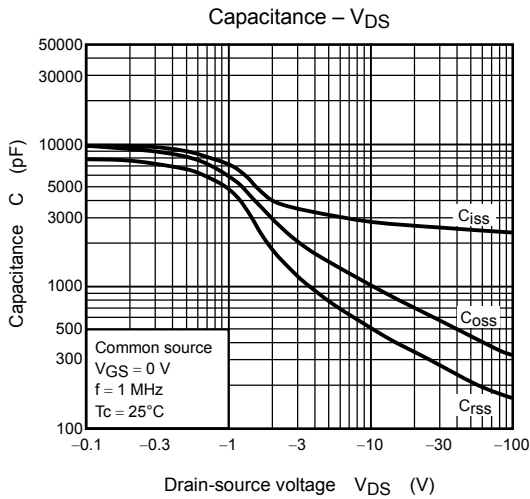
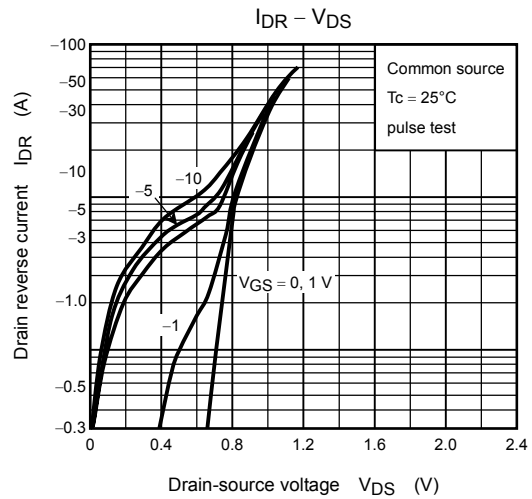
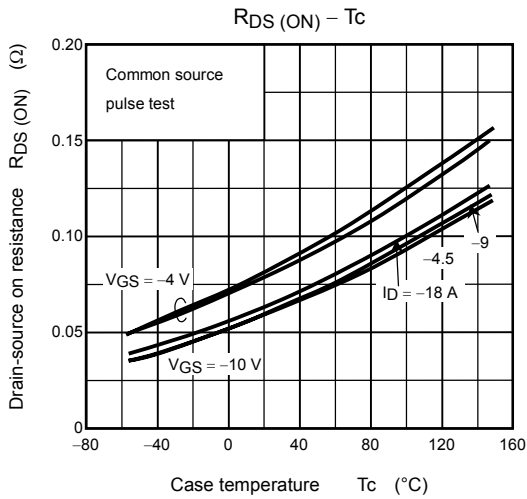
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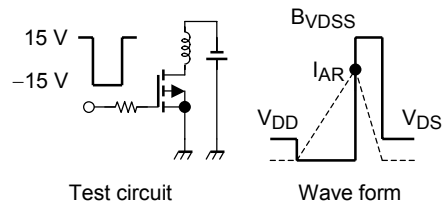
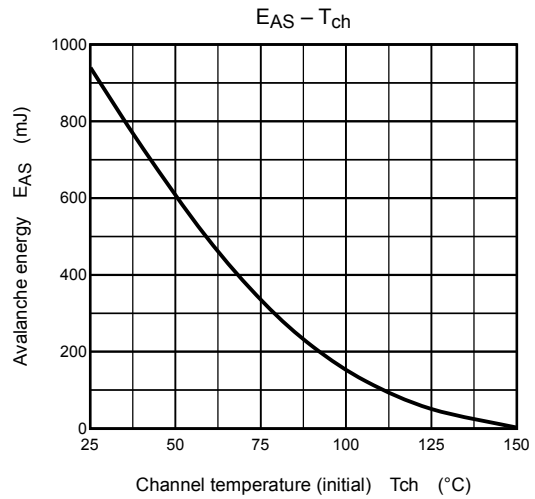
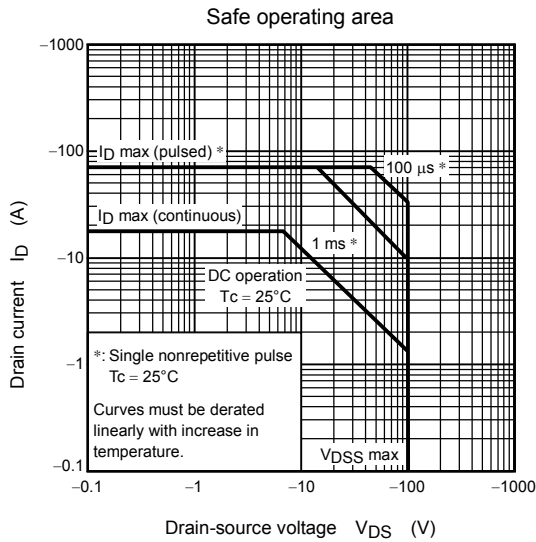
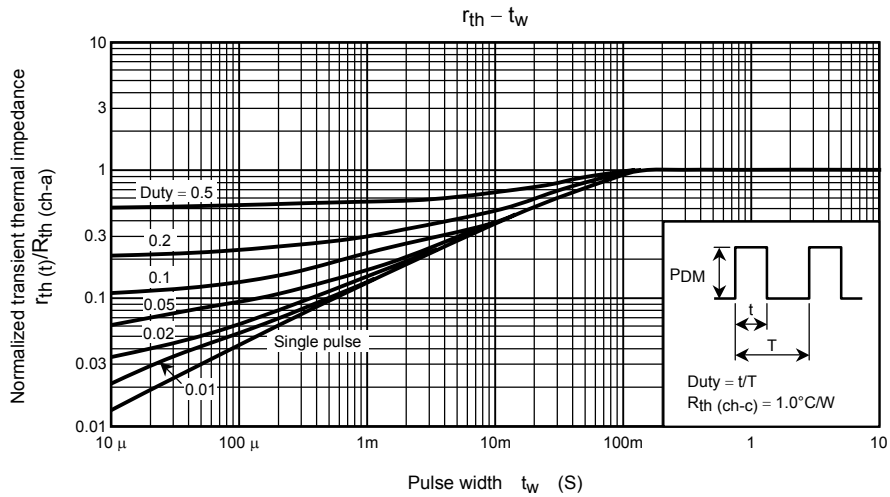
※ Lot Number

Month (starting from alphabet A)

Year (last number of the christian era)







$$R_G = 25 \Omega$$

$$V_{DD} = -50 \text{ V}, L = 3.56 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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